

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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MSD6100

Dual Switching Diode Common Cathode

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS (EACH DIODE)

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	100	Vdc
Recurrent Peak Forward Current	ΙF	200	mAdc
Peak Forward Surge Current (Pulse Width = 10 μsec)	I _{FM(surge)}	500	mAdc
Total Device Dissipation @ T _A = 25°C (Note 1) Derate above = 25°C		625 5.0	mW mW/°C
Operating and Storage Junction Temperature Range (Note 1)	T _J , T _{stg}	-55 to +135	°C

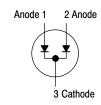
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Continuous package improvements have enhanced these guaranteed Maximum Ratings as follows: P_D = 1.0 W @ T_C = 25°C, Derate above 25°C – 8.0 mW/°C, T_J = –65 to +150°C, θ JC = 125°C/W.



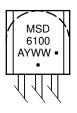
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



MSD6100 = Device Code

A = Assembly Location

Y = Year WW = Work Week = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping
MSD6100	TO-92	5000 Units / Box
MSD6100G	TO-92 (Pb-Free)	5000 Units / Box
MSD6100RLRA	TO-92	2000/Tape & Reel
MSD6100RLRAG	TO-92 (Pb-Free)	2000/Tape & Reel

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MSD6100

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Max	Unit
Breakdown Voltage (I _(BR) = 100 μAdc)	V _(BR)	100	-	Vdc
Reverse Current	I _R	- - -	5.0 0.1 50	μAdc
Forward Voltage $ \begin{aligned} (I_F &= 1.0 \text{ mAdc}) \\ (I_F &= 10 \text{ mAdc}) \\ (I_F &= 100 \text{ mAdc}) \end{aligned} $	V _F	0.55 0.67 0.75	0.7 0.82 1.1	Vdc
Capacitance (V _R = 0)	С	-	1.5	pF
Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}$, $V_R = 5.0 \text{ Vdc}$, $i_{rr} = 1.0 \text{ mAdc}$)	t _{rr}	-	4.0	ns

TYPICAL CHARACTERISTICS

Curves Applicable to Each Anode

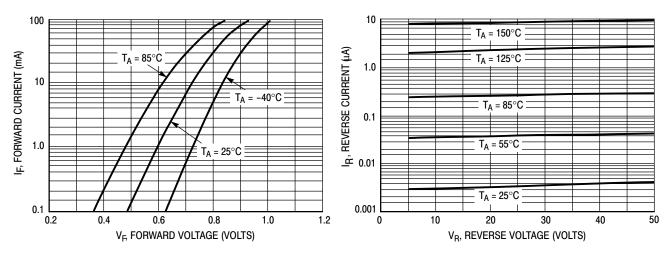


Figure 1. Forward Voltage

Figure 2. Leakage Current

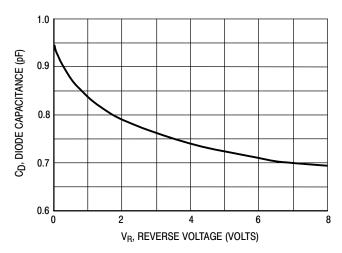
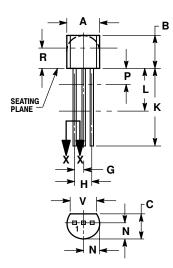


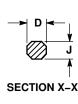
Figure 3. Capacitance

MSD6100

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 V14 5M 1982
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35	-	
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
٧	0.135		3.43		

STYLE 3:

PIN 1. ANODE 2. ANODE 3. CATHODE

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